

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Group Art Unit: 2812

Examiner: MULPURI, Savitri

P.T.O. Confirmation No.: 7536

METHOD OF FORMING NITRIDE-BASED SEMICONDUCTOR LAYER, AND METHOD OF MANUFACTURING NITRIDE-BASED SEMICONDUCTOR

DEVICE

Serial No.: 09/941,982

Filed: August 30, 2001

In re the Application of: KANO, Takashi et al.

PETITION FOR EXTENSION OF TIME

Commissioner for Patents P.O. Box 1450

Alexandria, VA 22313-1450

Date: July 8, 2003

Sir:

For.

Applicants petition the Commissioner for Patents to extend the time for response to the Office Action dated January 8, 2003 for three months from April 8, 2003 to July 8, 2003.

Attached please find a check in the amount of \$840.00 to cover the cost of the extension for a large entity (2 months \$410.0 already paid on June 9, 2003). In the event that any additional fees are due in connection with this paper, please charge our Deposit Account No. 01-2340.

Respectfully submitted,

ARMSTRONG, WESTERMAN & HATTORI, LLP

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520,00 OP

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PATENT TRADEMARK OFFICE